

## RF Power Field Effect Transistors

### N-Channel Enhancement-Mode Lateral MOSFETs

Designed for Class A or Class AB general purpose applications with frequencies from 1600 to 2200 MHz. Suitable for analog and digital modulation and multipurpose amplifier applications.

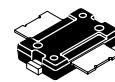
- Typical Two-Tone Performance @ 2170 MHz:  $V_{DD} = 28$  Volts,  $I_{DQ} = 130$  mA,  $P_{out} = 10$  Watts PEP  
Power Gain — 15.5 dB  
Drain Efficiency — 36%  
IMD — -34 dBc
- Typical 2-Carrier W-CDMA Performance:  $V_{DD} = 28$  Volts,  $I_{DQ} = 130$  mA,  $P_{out} = 1$  Watt Avg., Full Frequency Band (2130-2170 MHz), Channel Bandwidth = 3.84 MHz. PAR = 8.5 dB @ 0.01% Probability  
Power Gain — 15.5 dB  
Drain Efficiency — 15%  
IM3 @ 10 MHz Offset — -47 dBc in 3.84 MHz Channel Bandwidth  
ACPR @ 5 MHz Offset — -49 dBc in 3.84 MHz Channel Bandwidth
- Typical Single-Carrier N-CDMA Performance:  $V_{DD} = 28$  Volts,  $I_{DQ} = 130$  mA,  $P_{out} = 1$  Watt Avg., Full Frequency Band (1930-1990 MHz), IS-95 (Pilot, Sync, Paging, Traffic Codes 8 through 13), Channel Bandwidth = 1.2288 MHz. PAR = 9.8 dB @ 0.01% Probability on CCDF.  
Power Gain — 15.5 dB  
Drain Efficiency — 16%  
ACPR @ 885 kHz Offset = -60 dBc in 30 kHz Bandwidth
- Typical GSM EDGE Performance:  $V_{DD} = 28$  Volts,  $I_{DQ} = 130$  mA,  $P_{out} = 4$  Watts Avg., Full Frequency Band (1805-1880 MHz)  
Power Gain — 16 dB  
Drain Efficiency — 33%  
EVM — 1.3% rms
- Capable of Handling 5:1 VSWR, @ 28 Vdc, 2000 MHz, 10 Watts CW Output Power

#### Features

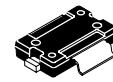
- Characterized with Series Equivalent Large-Signal Impedance Parameters
- Internally Matched for Ease of Use
- Qualified Up to a Maximum of 32  $V_{DD}$  Operation
- Integrated ESD Protection
- 225°C Capable Plastic Package
- RoHS Compliant
- In Tape and Reel. R1 Suffix = 500 Units per 24 mm, 13 inch Reel.

**MRF6S20010NR1**  
**MRF6S20010GNR1**

**1600-2200 MHz, 10 W, 28 V**  
**GSM, GSM EDGE**  
**SINGLE N-CDMA**  
**2 x W-CDMA**  
**LATERAL N-CHANNEL**  
**RF POWER MOSFETs**



**CASE 1265-09, STYLE 1**  
**TO-270-2**  
**PLASTIC**  
**MRF6S20010NR1**



**CASE 1265A-03, STYLE 1**  
**TO-270-2 GULL**  
**PLASTIC**  
**MRF6S20010GNR1**

**Table 1. Maximum Ratings**

| Rating                               | Symbol    | Value       | Unit |
|--------------------------------------|-----------|-------------|------|
| Drain-Source Voltage                 | $V_{DSS}$ | -0.5, +68   | Vdc  |
| Gate-Source Voltage                  | $V_{GS}$  | -0.5, +12   | Vdc  |
| Storage Temperature Range            | $T_{stg}$ | -65 to +150 | °C   |
| Case Operating Temperature           | $T_c$     | 150         | °C   |
| Operating Junction Temperature (1,2) | $T_j$     | 225         | °C   |

- Continuous use at maximum temperature will affect MTTF.
- MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.

**Table 2. Thermal Characteristics**

| Characteristic  | Symbol           | Value (1,2) | Unit |
|---|------------------|-------------|------|
| Thermal Resistance, Junction to Case<br>Case Temperature 78°C, 1 W CW<br>Case Temperature 79°C, 10 W PEP, Two-Tone Test | R <sub>θJC</sub> | 2.5<br>5.9  | °C/W |

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class        |
|---------------------------------------|--------------|
| Human Body Model (per JESD22-A114)    | 1A (Minimum) |
| Machine Model (per EIA/JESD22-A115)   | A (Minimum)  |
| Charge Device Model (per JESD22-C101) | IV (Minimum) |

**Table 4. Moisture Sensitivity Level**

| Test Methodology                     | Rating | Package Peak Temperature | Unit |
|--------------------------------------|--------|--------------------------|------|
| Per JESD22-A113, IPC/JEDEC J-STD-020 | 3      | 260                      | °C   |

**Table 5. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics**

|   |                  |   |   |     |      |
|---|------------------|---|---|-----|------|
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 68 \text{ Vdc}$ , $V_{GS} = 0 \text{ Vdc}$ ) | I <sub>DSS</sub> | — | — | 10  | μAdc |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 28 \text{ Vdc}$ , $V_{GS} = 0 \text{ Vdc}$ ) | I <sub>DSS</sub> | — | — | 1   | μAdc |
| Gate-Source Leakage Current<br>( $V_{GS} = 5 \text{ Vdc}$ , $V_{DS} = 0 \text{ Vdc}$ )              | I <sub>GSS</sub> | — | — | 500 | μAdc |

**On Characteristics**

|   |                     |     |      |     |     |
|---|---------------------|-----|------|-----|-----|
| Gate Threshold Voltage<br>( $V_{DS} = 10 \text{ Vdc}$ , $I_D = 40 \text{ μAdc}$ )                             | V <sub>GS(th)</sub> | 1.5 | 2.2  | 3.5 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 28 \text{ Vdc}$ , $I_D = 130 \text{ mA}$ , Measured in Functional Test) | V <sub>GS(Q)</sub>  | 2   | 2.8  | 4   | Vdc |
| Drain-Source On-Voltage<br>( $V_{GS} = 10 \text{ Vdc}$ , $I_D = 0.4 \text{ Adc}$ )                            | V <sub>DS(on)</sub> | —   | 0.33 | 0.4 | Vdc |

**Dynamic Characteristics (3)**

|   |                  |   |      |   |    |
|---|------------------|---|------|---|----|
| Output Capacitance<br>( $V_{DS} = 28 \text{ Vdc} \pm 30 \text{ mV(rms)}$ ac @ 1 MHz, $V_{GS} = 0 \text{ Vdc}$ )           | C <sub>oss</sub> | — | 20   | — | pF |
| Reverse Transfer Capacitance<br>( $V_{DS} = 28 \text{ Vdc} \pm 30 \text{ mV(rms)}$ ac @ 1 MHz, $V_{GS} = 0 \text{ Vdc}$ ) | C <sub>rss</sub> | — | 11.6 | — | pF |
| Input Capacitance<br>( $V_{DS} = 28 \text{ Vdc}$ , $V_{GS} = 0 \text{ Vdc} \pm 30 \text{ mV(rms)}$ ac @ 1 MHz)            | C <sub>iss</sub> | — | 120  | — | pF |

**Functional Tests (4)** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 28 \text{ Vdc}$ ,  $I_{DQ} = 130 \text{ mA}$ ,  $P_{out} = 10 \text{ W PEP}$ ,  $f_1 = 2170 \text{ MHz}$ ,  $f_2 = 2170.1 \text{ MHz}$ , Two-Tone Test

|                            |                 |    |      |     |     |
|----------------------------|-----------------|----|------|-----|-----|
| Power Gain                 | G <sub>ps</sub> | 14 | 15.5 | 17  | dB  |
| Drain Efficiency           | η <sub>D</sub>  | 33 | 36   | —   | %   |
| Intermodulation Distortion | IMD             | —  | -34  | -28 | dBc |
| Input Return Loss          | IRL             | —  | -15  | -9  | dB  |

- MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
- Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.
- Part internally matched on input.
- Measurement made with device in straight lead configuration before any lead forming operation is applied.

(continued)

**Table 5. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (continued)

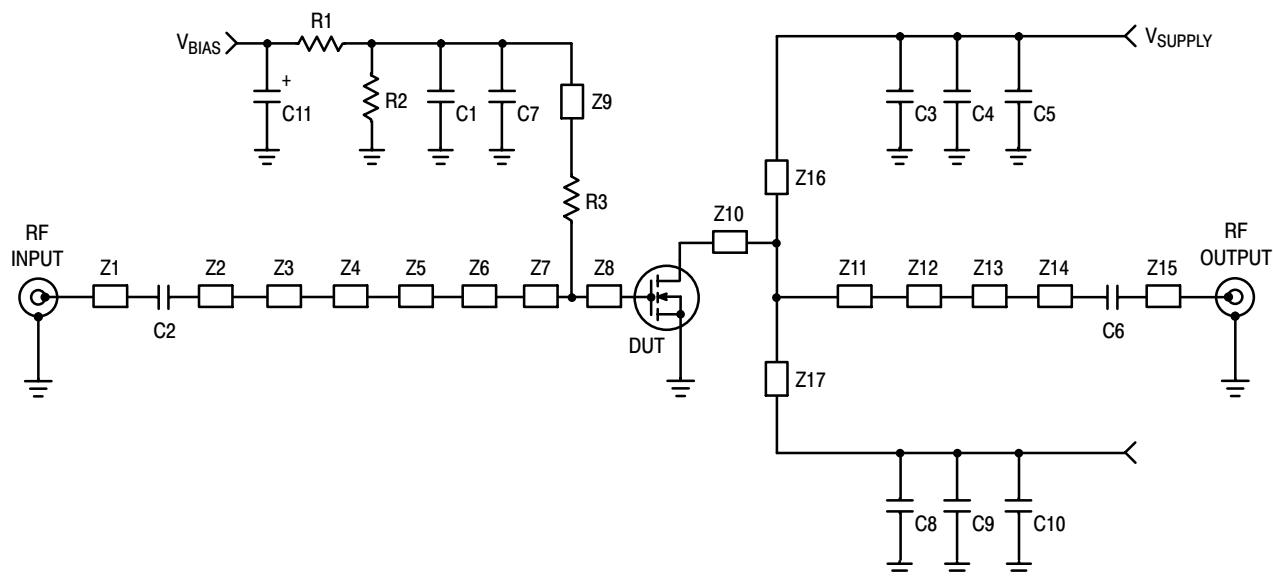
| Characteristic   | Symbol   | Min | Typ  | Max | Unit |
|--|----------|-----|------|-----|------|
| <b>Typical 2-Carrier W-CDMA Performances</b> (In Freescale CDMA Test Fixture, 50 ohm system) $V_{DD} = 28 \text{ Vdc}$ , $I_{DQ} = 130 \text{ mA}$ , $P_{out} = 1 \text{ W Avg.}$ , $f_1 = 2112.5 \text{ MHz}$ , $f_2 = 2122.5 \text{ MHz}$ and $f_1 = 2157.5 \text{ MHz}$ , $f_2 = 2167.5 \text{ MHz}$ , 2-Carrier W-CDMA, 3.84 MHz Channel Bandwidth Carriers. ACPR measured in 3.84 MHz Channel Bandwidth @ $\pm 5 \text{ MHz}$ Offset. IM3 measured in 3.84 MHz Bandwidth @ $\pm 10 \text{ MHz}$ Offset. PAR = 8.5 dB @ 0.01% Probability on CCDF. |          |     |      |     |      |
| Power Gain   | $G_{ps}$ | —   | 15.5 | —   | dB   |
| Drain Efficiency   | $\eta_D$ | —   | 15   | —   | %    |
| Gain Flatness in 30 MHz Bandwidth @ $P_{out} = 1 \text{ W CW}$   | $G_F$    | —   | 0.3  | —   | dB   |
| Intermodulation Distortion   | IM3      | —   | -47  | —   | dBc  |
| Adjacent Channel Power Ratio   | ACPR     | —   | -49  | —   | dBc  |

**Typical N-CDMA Performances** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 28 \text{ Vdc}$ ,  $I_{DQ} = 130 \text{ mA}$ ,  $P_{out} = 1 \text{ W Avg.}$ , 1930 MHz < Frequency < 1990 MHz, Single-Carrier N-CDMA, 1.2288 MHz Channel Bandwidth Carrier. ACPR measured in 30 kHz Channel Bandwidth @  $\pm 885 \text{ kHz}$  Offset. PAR = 9.8 dB @ 0.01% Probability on CCDF

|  |          |   |      |   |     |
|--|----------|---|------|---|-----|
| Power Gain   | $G_{ps}$ | — | 15.5 | — | dB  |
| Drain Efficiency   | $\eta_D$ | — | 16   | — | %   |
| Gain Flatness in 30 MHz Bandwidth @ $P_{out} = 1 \text{ W CW}$ | $G_F$    | — | 0.3  | — | dB  |
| Adjacent Channel Power Ratio                                   | ACPR     | — | -60  | — | dBc |

**Typical GSM EDGE Performances** (In Freescale GSM EDGE Test Fixture, 50 ohm system)  $V_{DD} = 28 \text{ Vdc}$ ,  $I_{DQ} = 130 \text{ mA}$ ,  $P_{out} = 4 \text{ W Avg.}$ , 1805 - 1880 MHz, EDGE Modulation

|  |          |   |     |   |       |
|--|----------|---|-----|---|-------|
| Power Gain   | $G_{ps}$ | — | 16  | — | dB    |
| Drain Efficiency   | $\eta_D$ | — | 33  | — | %     |
| Gain Flatness in 30 MHz Bandwidth @ $P_{out} = 4 \text{ W CW}$ | $G_F$    | — | 0.3 | — | dB    |
| Error Vector Magnitude   | EVM      | — | 1.3 | — | % rms |
| Spectral Regrowth at 400 kHz Offset                            | SR1      | — | -60 | — | dBc   |
| Spectral Regrowth at 600 kHz Offset                            | SR2      | — | -70 | — | dBc   |

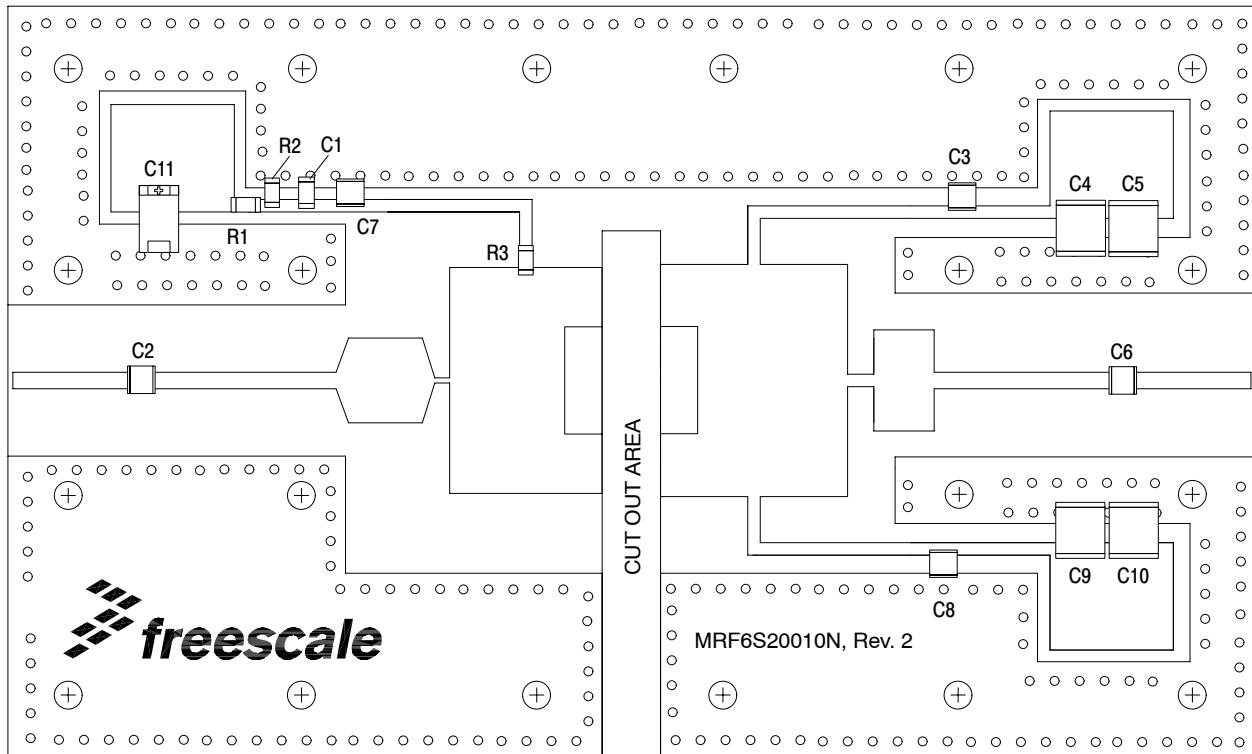


|         |                                |          |   |
|---------|--------------------------------|----------|---|
| Z1, Z15 | 0.066" x 0.480" Microstrip     | Z10      | 0.930" x 0.350" Microstrip                |
| Z2      | 0.066" x 0.765" Microstrip     | Z11      | 0.930" x 0.400" Microstrip                |
| Z3, Z5  | 0.066" x 0.340" x 0.050" Taper | Z12      | 0.050" x 0.105" Microstrip                |
| Z4      | 0.340" x 0.295" Microstrip     | Z13      | 0.405" x 0.242" Microstrip                |
| Z6      | 0.020" x 0.060" Microstrip     | Z14      | 0.066" x 0.740" Microstrip                |
| Z7      | 0.0905" x 0.280" Microstrip    | Z16, Z17 | 0.050" x 1.250" Microstrip                |
| Z8      | 0.0905" x 0.330" Microstrip    | PCB      | Taconic RF-35, 0.030", $\epsilon_r = 3.5$ |
| Z9      | 0.050" x 0.980" Microstrip     |          |   |

Figure 1. MRF6S20010NR1(GNR1) Test Circuit Schematic — 2110-2170 MHz

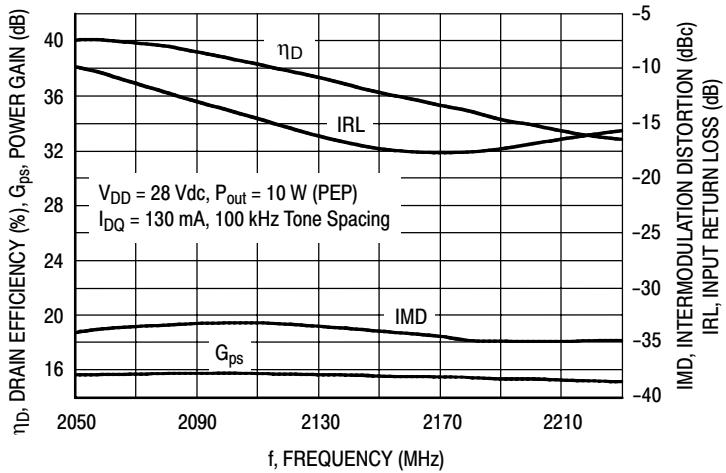
Table 6. MRF6S20010NR1(GNR1) Test Circuit Component Designations and Values — 2110-2170 MHz

| Part            | Description                              | Part Number        | Manufacturer |
|-----------------|--|--------------------|--------------|
| C1              | 100 nF Chip Capacitor                    | CDR33BX104AKYS     | Kemet        |
| C2, C6          | 4.7 pF Chip Capacitors                   | ATC100B4R7CT500XT  | ATC          |
| C3, C7, C8      | 9.1 pF Chip Capacitors                   | ATC100B9R1CT500XT  | ATC          |
| C4, C5, C9, C10 | 10 $\mu$ F, 50 V Chip Capacitors         | GRM55DR61H106KA88B | Murata       |
| C11             | 10 $\mu$ F, 35 V Tantalum Chip Capacitor | T490D106K035AT     | Kemet        |
| R1              | 1 k $\Omega$ , 1/4 W Chip Resistor       | CRCW12061001FKEA   | Vishay       |
| R2              | 10 k $\Omega$ , 1/4 W Chip Resistor      | CRCW12061002FKEA   | Vishay       |
| R3              | 10 $\Omega$ , 1/4 W Chip Resistor        | CRCW120610R0FKEA   | Vishay       |

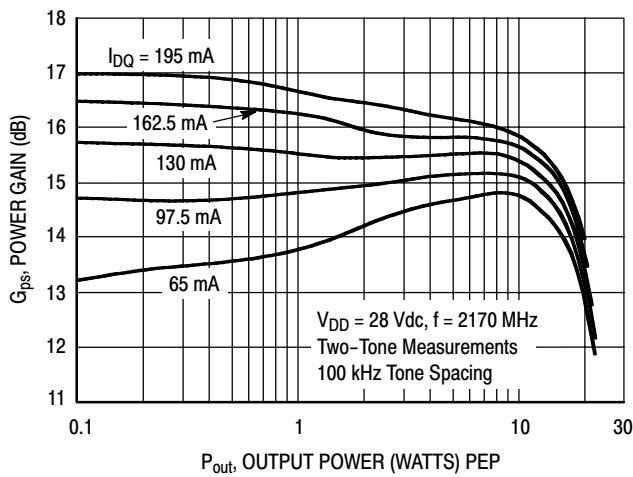


**Figure 2. MRF6S20010NR1(GNR1) Test Circuit Component Layout — 2110-2170 MHz**

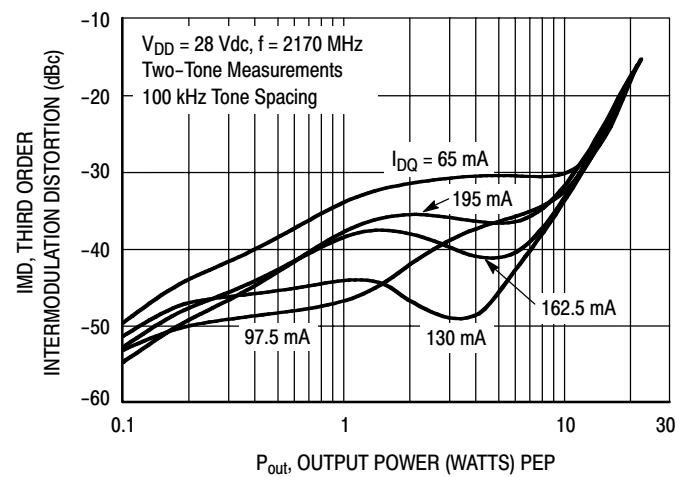
## TYPICAL CHARACTERISTICS — 2110-2170 MHz



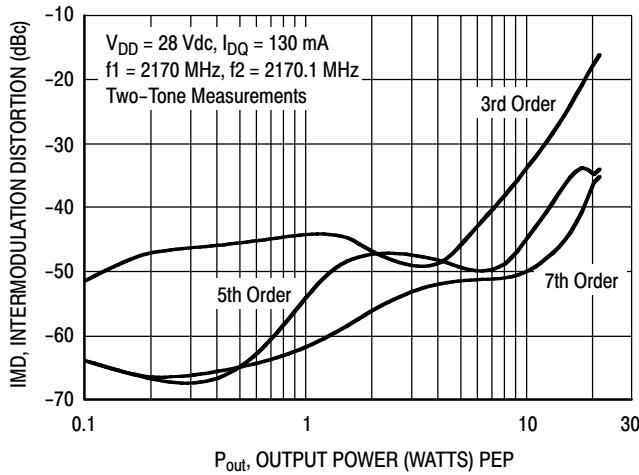
**Figure 3. Two-Tone Wideband Performance  
@  $P_{out} = 10$  Watts (PEP)**



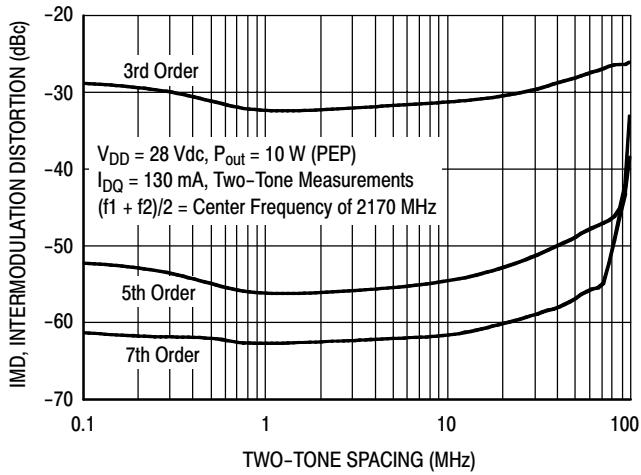
**Figure 4. Two-Tone Power Gain versus  
Output Power**



**Figure 5. Third Order Intermodulation  
Distortion versus Output Power**

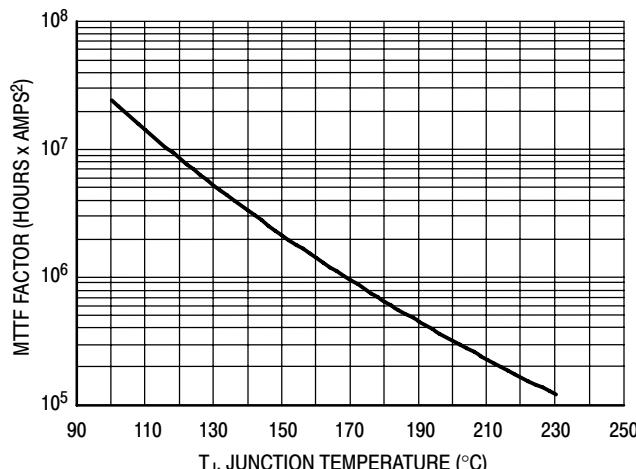
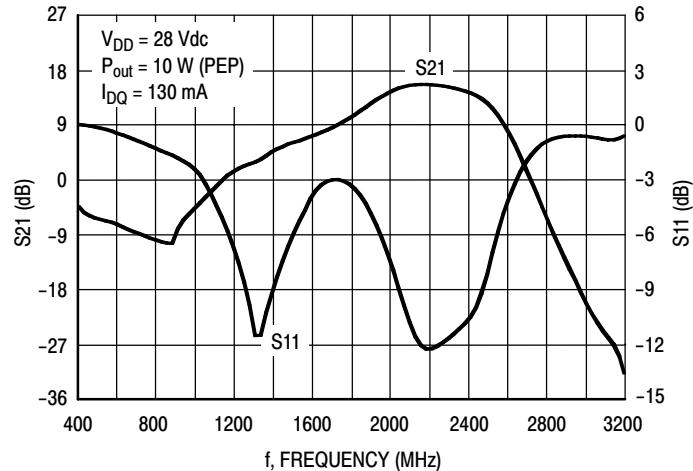
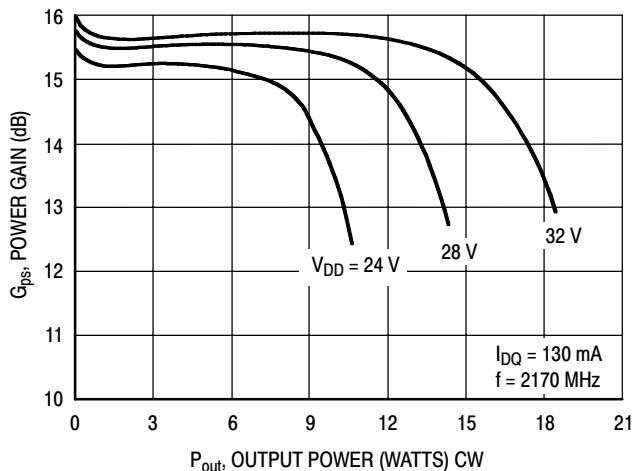
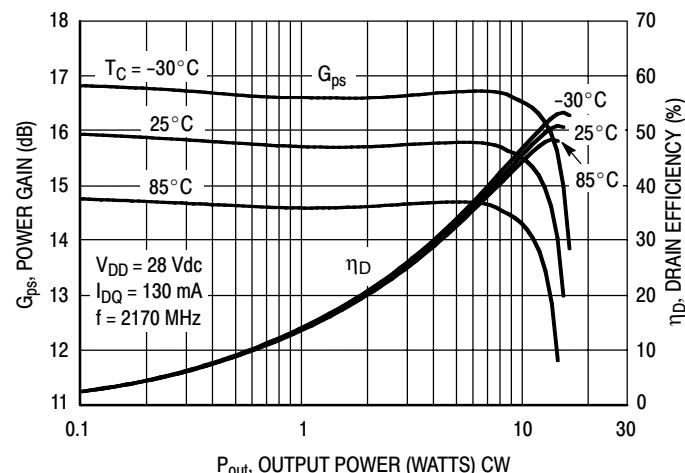
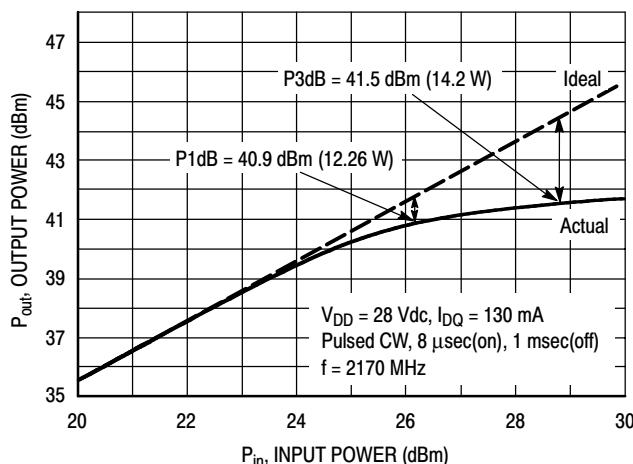


**Figure 6. Intermodulation Distortion Products  
versus Output Power**



**Figure 7. Intermodulation Distortion Products  
versus Tone Spacing**

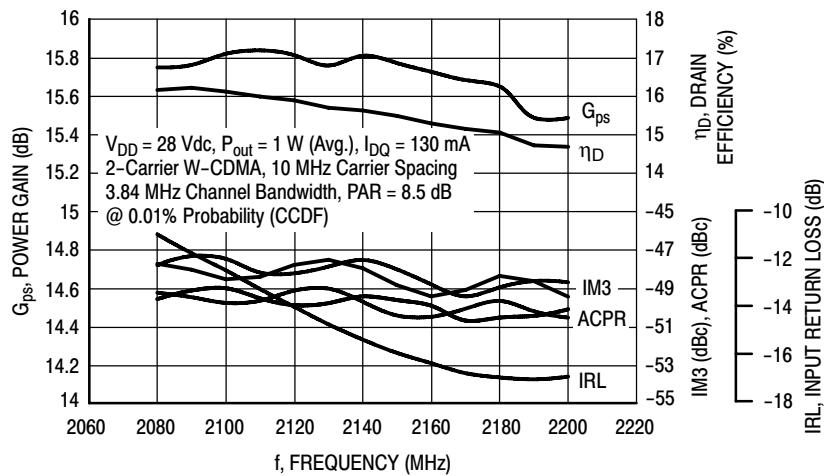
## TYPICAL CHARACTERISTICS — 2110-2170 MHz



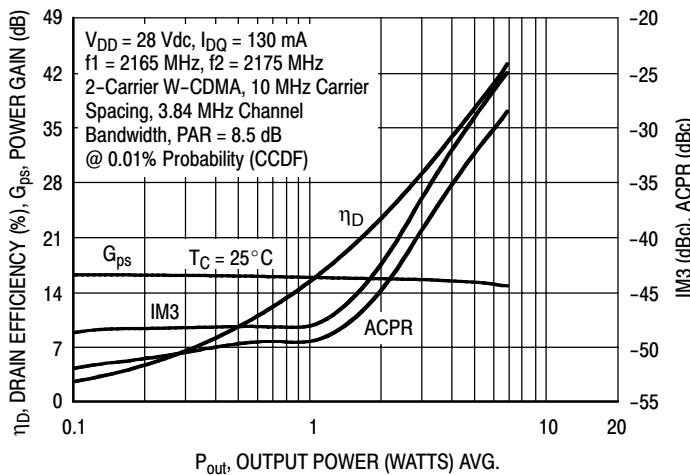
This above graph displays calculated MTTF in hours when the device is operated at  $V_{DD} = 28$  Vdc,  $P_{out} = 10$  W PEP, and  $\eta_D = 36\%$ .

MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.

## W-CDMA TYPICAL CHARACTERISTICS — 2110-2170 MHz

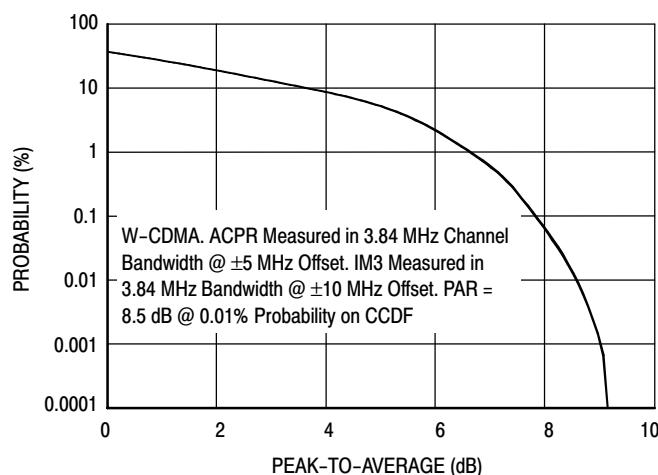


**Figure 13. 2-Carrier W-CDMA Broadband Performance  
@  $P_{out} = 1$  Watt Avg.**

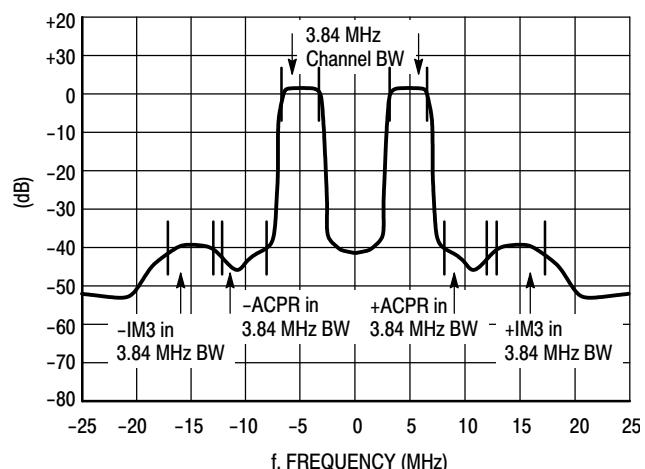


**Figure 14. 2-Carrier W-CDMA ACPR, IM3, Power Gain  
and Drain Efficiency versus Output Power**

## W-CDMA TEST SIGNAL

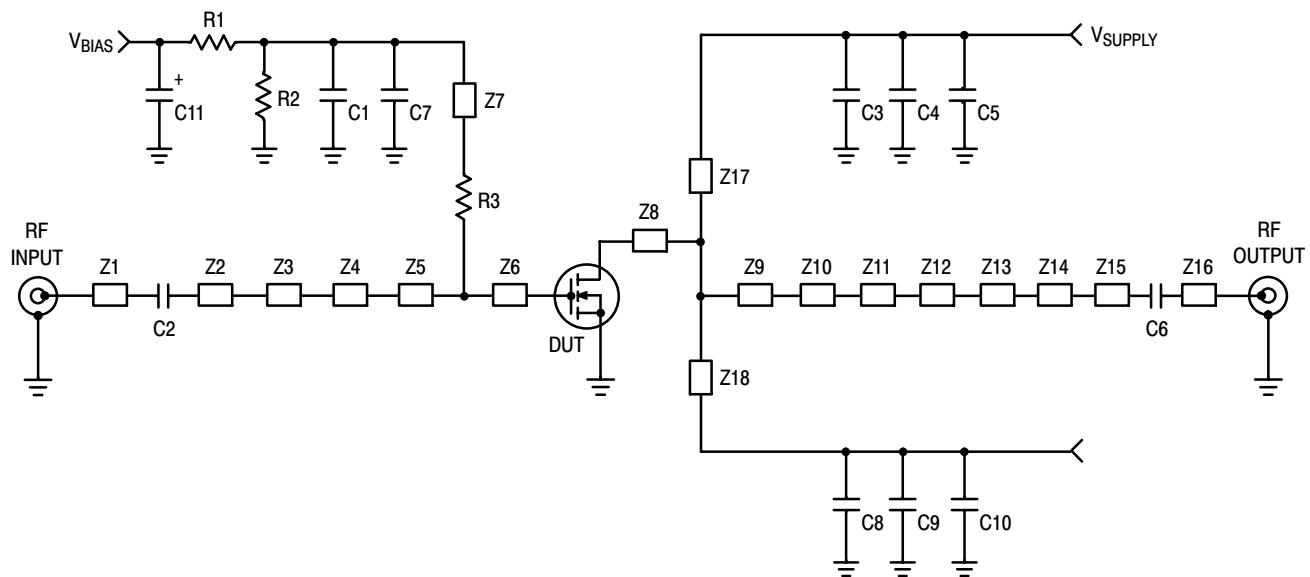


**Figure 15.** CCDF W-CDMA 3GPP, Test Model 1,  
64 DPCH, 67% Clipping, Single-Carrier Test Signal



**Figure 16.** 2-Carrier W-CDMA Spectrum

## N-CDMA TYPICAL CHARACTERISTICS — 1930-1990 MHz



|        |                            |          |   |
|--------|----------------------------|----------|---|
| Z1     | 0.066" x 0.480" Microstrip | Z11      | 0.244" x 0.423" Microstrip                |
| Z2     | 0.066" x 0.728" Microstrip | Z12      | 0.244" x 0.066" x 0.089" Taper            |
| Z3     | 0.354" x 0.512" Microstrip | Z13      | 0.066" x 0.182" Microstrip                |
| Z4     | 0.066" x 0.079" Microstrip | Z14      | 0.066" x 0.263" Microstrip                |
| Z5, Z6 | 0.591" x 0.335" Microstrip | Z15      | 0.236" x 0.118" Microstrip                |
| Z7     | 0.050" x 0.980" Microstrip | Z16      | 0.066" x 0.099" Microstrip                |
| Z8     | 1.142" x 0.350" Microstrip | Z17, Z18 | 0.050" x 1.250" Microstrip                |
| Z9     | 1.142" x 0.516" Microstrip | PCB      | Taconic RF-35, 0.030", $\epsilon_r = 3.5$ |
| Z10    | 0.433" x 0.276" Microstrip |          |   |

Figure 17. MRF6S20010NR1(GNR1) Test Circuit Schematic — 1930-1990 MHz

Table 7. MRF6S20010NR1(GNR1) Test Circuit Component Designations and Values — 1930-1990 MHz

| Part            | Description                              | Part Number       | Manufacturer |
|-----------------|--|-------------------|--------------|
| C1              | 100 nF Chip Capacitor                    | 12065C104KAT      | AVX          |
| C2, C6          | 4.7 pF Chip Capacitors                   | ATC100B4R7BT500XT | ATC          |
| C3, C7, C8      | 9.1 pF Chip Capacitors                   | ATC100B9R1BT500XT | ATC          |
| C4, C5, C9, C10 | 10 $\mu$ F Chip Capacitors               | C5750X5R1H106MT   | TDK          |
| C11             | 10 $\mu$ F, 35 V Tantalum Chip Capacitor | TAJD106K035R      | AVX          |
| R1, R2          | 10 k $\Omega$ , 1/4 W Chip Resistors     | CRCW12061002FKEA  | Vishay       |
| R3              | 10 $\Omega$ , 1/4 W Chip Resistor        | CRCW120610R0FKEA  | Vishay       |

## N-CDMA TYPICAL CHARACTERISTICS — 1930-1990 MHz

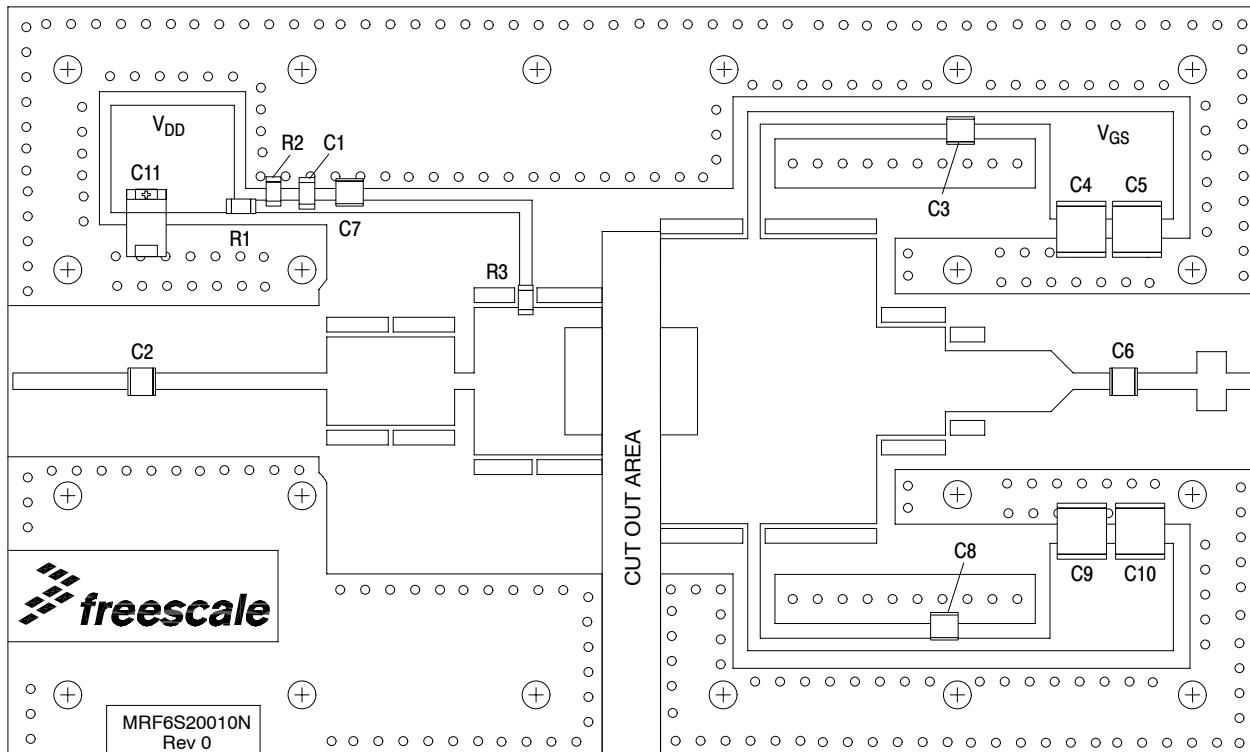


Figure 18. MRF6S20010NR1(GNR1) Test Circuit Component Layout — 1930-1990 MHz

## N-CDMA TYPICAL CHARACTERISTICS — 1930-1990 MHz

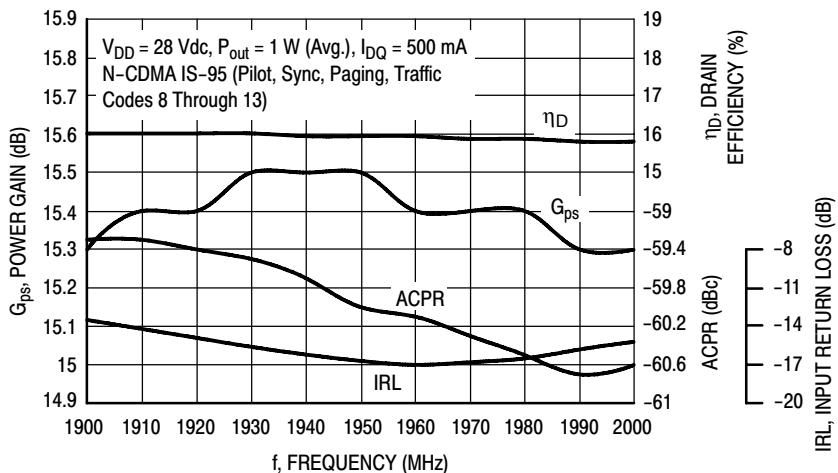


Figure 19. Single-Carrier N-CDMA Broadband Performance  
@  $P_{out} = 1$  Watt Avg.

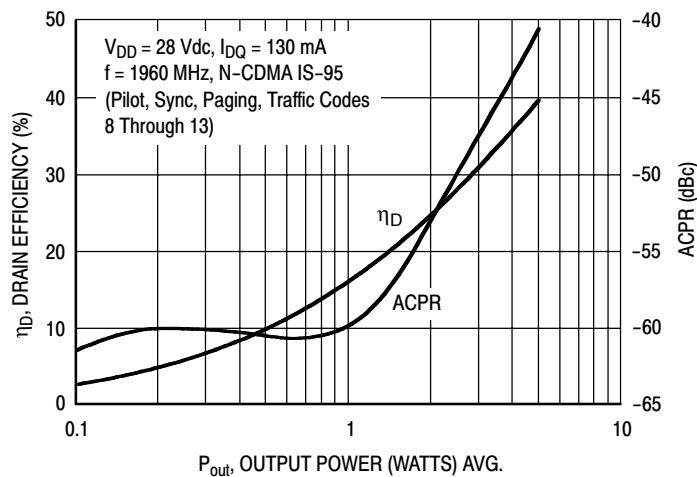
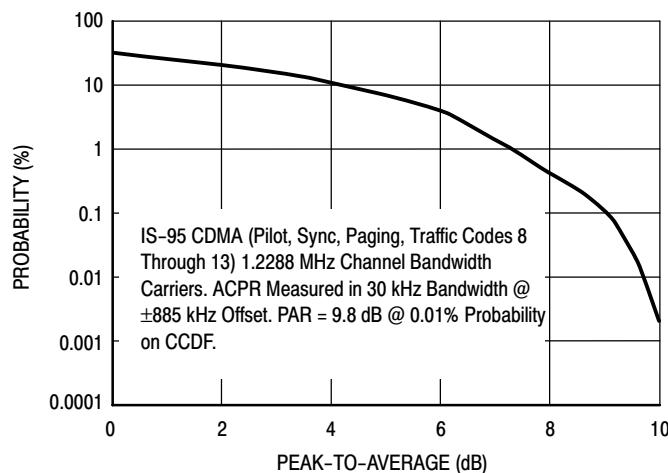
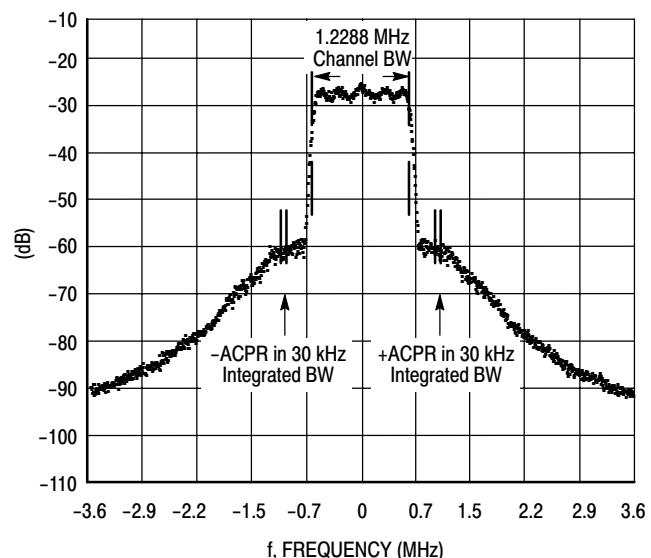


Figure 20. Single-Carrier N-CDMA ACPR and Drain Efficiency versus Output Power

## N-CDMA TEST SIGNAL

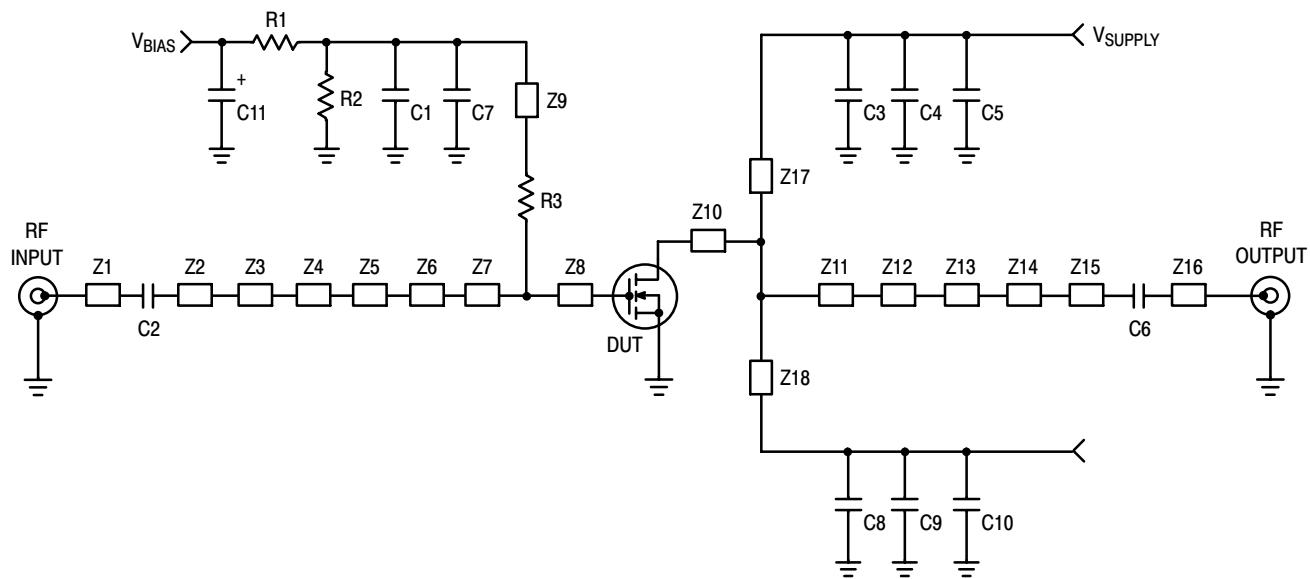


**Figure 21. Single-Carrier CCDF N-CDMA**



**Figure 22. Single-Carrier N-CDMA Spectrum**

## GSM EDGE TYPICAL CHARACTERISTICS — 1805-1880 MHz



|         |                            |          |   |
|---------|----------------------------|----------|---|
| Z1, Z16 | 0.066" x 0.480" Microstrip | Z10      | 1.142" x 0.350" Microstrip                |
| Z2      | 0.066" x 0.137" Microstrip | Z11      | 1.142" x 0.516" Microstrip                |
| Z3      | 0.236" x 0.236" Microstrip | Z12      | 0.433" x 0.276" Microstrip                |
| Z4      | 0.066" x 0.354" Microstrip | Z13      | 0.276" x 0.157" Microstrip                |
| Z5      | 0.551" x 0.512" Microstrip | Z14      | 0.236" x 0.433" Microstrip                |
| Z6      | 0.066" x 0.079" Microstrip | Z15      | 0.066" x 0.104" Microstrip                |
| Z7      | 0.591" x 0.189" Microstrip | Z17, Z18 | 0.050" x 1.250" Microstrip                |
| Z8      | 0.591" x 0.334" Microstrip | PCB      | Taconic RF-35, 0.030", $\epsilon_r = 3.5$ |
| Z9      | 0.050" x 0.980" Microstrip |          |   |

Figure 23. MRF6S20010NR1(GNR1) Test Circuit Schematic — 1805-1880 MHz

Table 8. MRF6S20010NR1(GNR1) Test Circuit Component Designations and Values —1805-1880 MHz

| Part            | Description                              | Part Number       | Manufacturer |
|-----------------|--|-------------------|--------------|
| C1              | 100 nF Chip Capacitor                    | 12065C104KAT      | AVX          |
| C2, C6          | 4.7 pF Chip Capacitors                   | ATC100B4R7BT500XT | ATC          |
| C3, C7, C8      | 9.1 pF Chip Capacitors                   | ATC100B9R1BT500XT | ATC          |
| C4, C5, C9, C10 | 10 $\mu$ F Chip Capacitors               | C5750X5R1H106MT   | TDK          |
| C11             | 10 $\mu$ F, 35 V Tantalum Chip Capacitor | TAJD106K035R      | AVX          |
| R1, R2          | 10 k $\Omega$ , 1/4 W Chip Resistors     | CRCW12061001FKEA  | Vishay       |
| R3              | 10 $\Omega$ , 1/4 W Chip Resistor        | CRCW120610R0FKEA  | Vishay       |

## GSM EDGE TYPICAL CHARACTERISTICS — 1805-1880 MHz

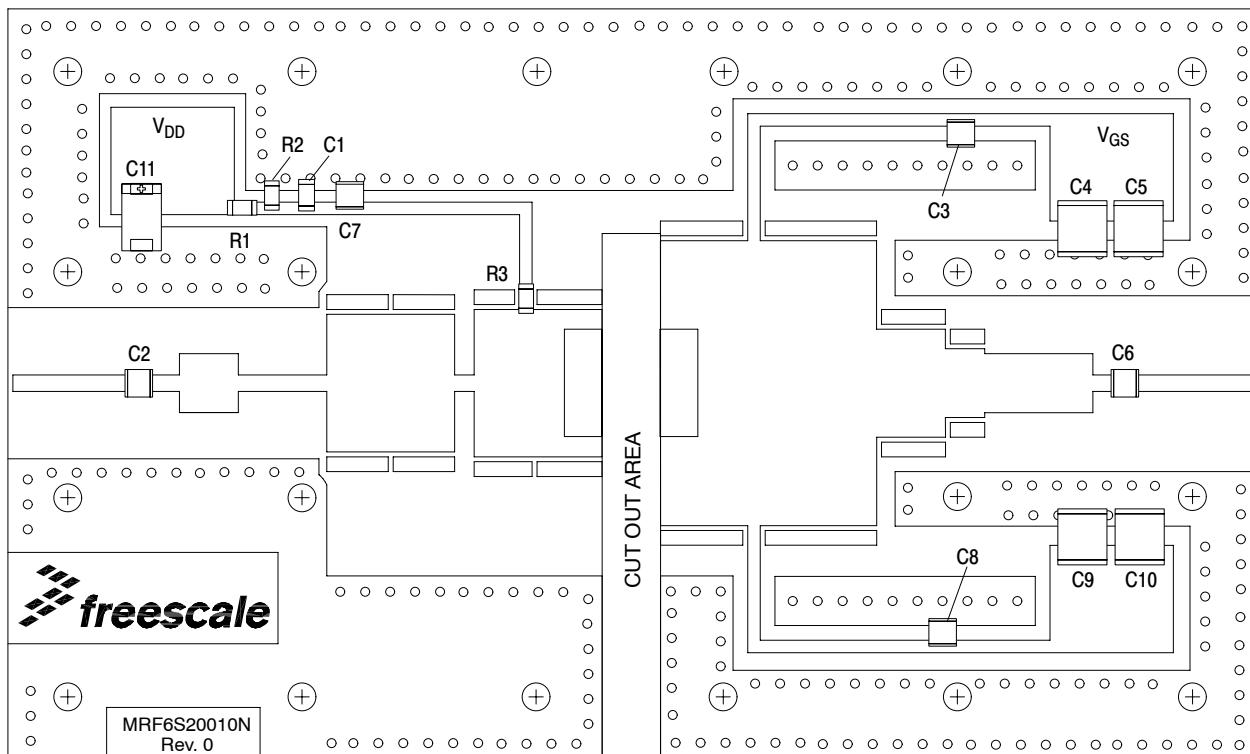


Figure 24. MRF6S20010NR1(GNR1) Test Circuit Component Layout — 1805-1880 MHz

**MRF6S20010NR1 MRF6S20010GNR1**

## GSM EDGE TYPICAL CHARACTERISTICS — 1805-1880 MHz

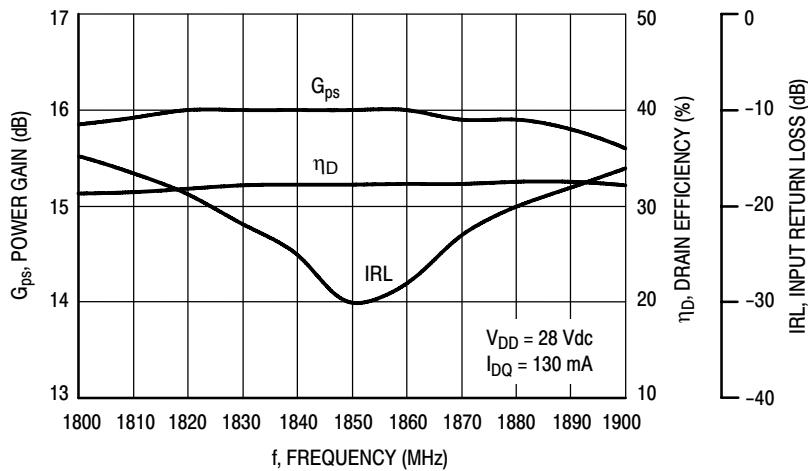


Figure 25. Power Gain, Input Return Loss and Drain Efficiency versus Frequency @  $P_{out} = 4$  Watts

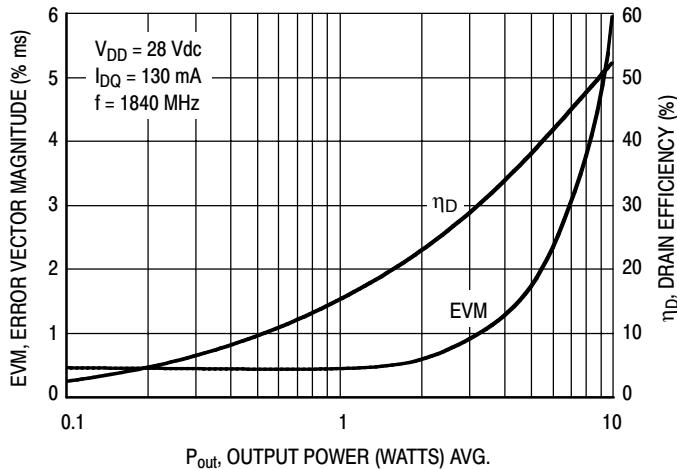


Figure 26. Error Vector Magnitude and Drain Efficiency versus Output Power

## GSM EDGE TEST SIGNAL

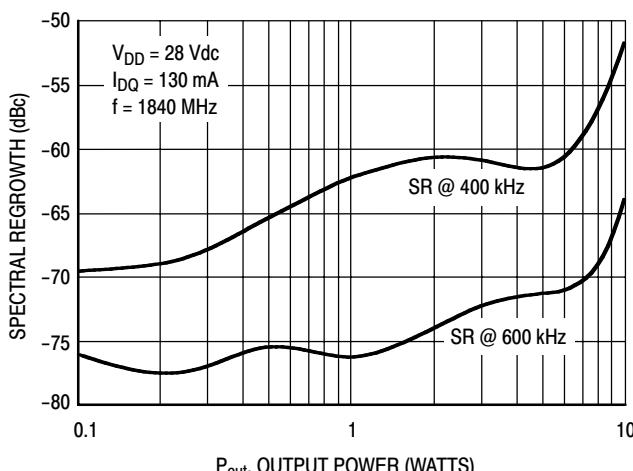


Figure 27. Spectral Regrowth at 400 kHz and 600 kHz versus Output Power

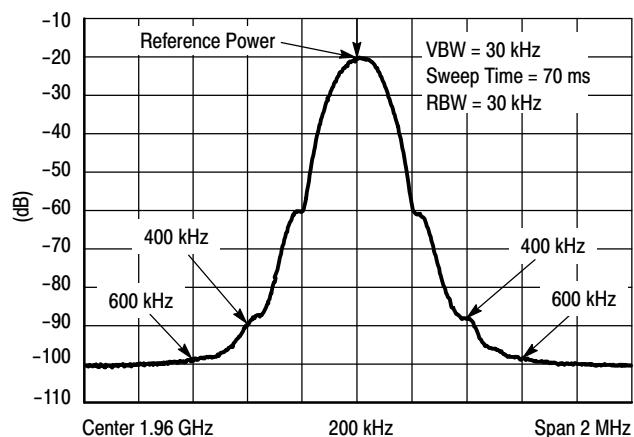
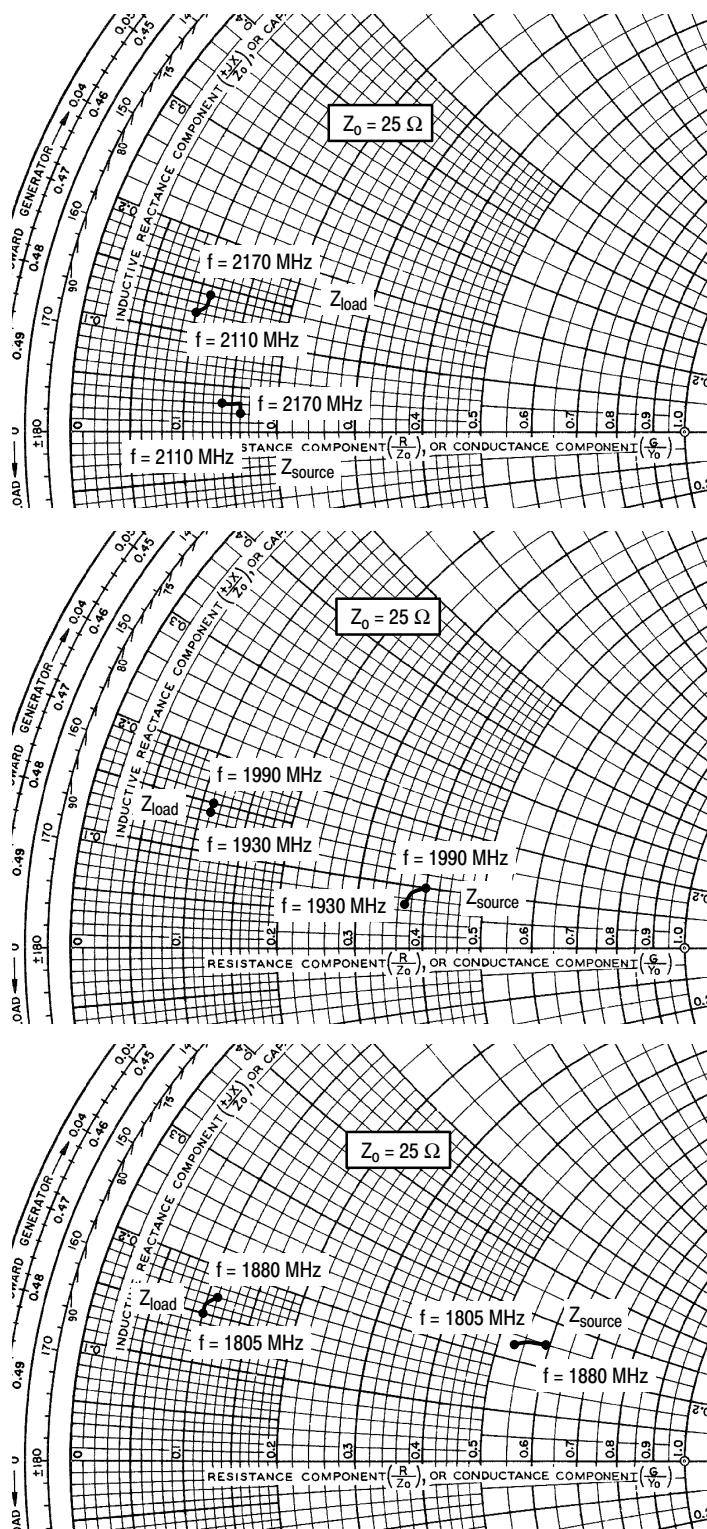


Figure 28. EDGE Spectrum



### 2170 MHz

$V_{DD} = 28$  Vdc,  $I_{DQ} = 130$  mA,  $P_{out} = 10$  W PEP

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 2110     | $3.619 + j0.792$         | $2.544 + j3.068$       |
| 2140     | $3.918 + j0.797$         | $2.673 + j3.291$       |
| 2170     | $4.087 + j0.558$         | $2.818 + j3.406$       |

### 1900 MHz

$V_{DD} = 28$  Vdc,  $I_{DQ} = 130$  mA,  $P_{out} = 1$  W Avg.

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 1930     | $9.237 + j1.849$         | $2.770 + j3.497$       |
| 1960     | $9.521 + j2.144$         | $2.754 + j3.668$       |
| 1990     | $9.889 + j2.434$         | $2.772 + j3.833$       |

### 1800 MHz

$V_{DD} = 28$  Vdc,  $I_{DQ} = 130$  mA,  $P_{out} = 4$  W Avg.

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 1805     | $13.237 + j5.810$        | $2.445 + j3.698$       |
| 1840     | $13.953 + j6.084$        | $2.542 + j3.942$       |
| 1880     | $14.858 + j6.279$        | $2.695 + j4.170$       |

$Z_{source}$  = Test circuit impedance as measured from gate to ground.

$Z_{load}$  = Test circuit impedance as measured from drain to ground.

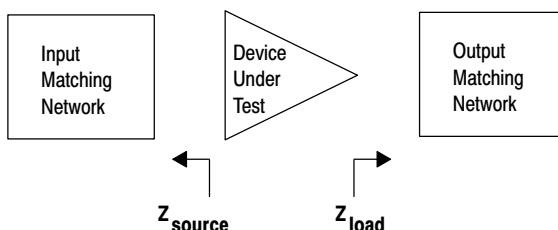


Figure 29. Series Equivalent Source and Load Impedance

**Table 9. Common Source Scattering Parameters** ( $V_{DD} = 28$  V,  $I_{DQ} = 126$  mA,  $T_A = 25^\circ\text{C}$ , 50 ohm system)

| f<br>MHz | <b>S<sub>11</sub></b> |               | <b>S<sub>21</sub></b> |               | <b>S<sub>12</sub></b> |               | <b>S<sub>22</sub></b> |               |
|----------|-----------------------|---------------|-----------------------|---------------|-----------------------|---------------|-----------------------|---------------|
|          | S <sub>11</sub>       | $\angle \phi$ | S <sub>21</sub>       | $\angle \phi$ | S <sub>12</sub>       | $\angle \phi$ | S <sub>22</sub>       | $\angle \phi$ |
| 500      | 0.984                 | -178.1        | 1.195                 | 42.42         | 0.001                 | -129.1        | 0.875                 | -116.3        |
| 550      | 0.986                 | -179.0        | 0.947                 | 40.48         | 0.001                 | -159.2        | 0.892                 | -121.6        |
| 600      | 0.985                 | 179.9         | 0.747                 | 39.66         | 0.001                 | 147.4         | 0.905                 | -125.9        |
| 650      | 0.986                 | 178.9         | 0.581                 | 39.89         | 0.001                 | 119.1         | 0.913                 | -129.9        |
| 700      | 0.982                 | 177.9         | 0.446                 | 41.80         | 0.001                 | 108.1         | 0.927                 | -133.4        |
| 750      | 0.983                 | 177.2         | 0.336                 | 46.70         | 0.002                 | 102.9         | 0.935                 | -136.4        |
| 800      | 0.983                 | 176.5         | 0.248                 | 56.02         | 0.002                 | 96.99         | 0.941                 | -139.5        |
| 850      | 0.979                 | 175.5         | 0.188                 | 72.74         | 0.003                 | 97.40         | 0.947                 | -141.9        |
| 900      | 0.980                 | 174.8         | 0.168                 | 96.69         | 0.003                 | 94.63         | 0.951                 | -144.4        |
| 950      | 0.977                 | 174.0         | 0.183                 | 119.3         | 0.004                 | 91.92         | 0.955                 | -146.6        |
| 1000     | 0.978                 | 173.2         | 0.223                 | 134.3         | 0.004                 | 92.80         | 0.960                 | -148.6        |
| 1050     | 0.972                 | 172.4         | 0.276                 | 142.2         | 0.004                 | 89.92         | 0.962                 | -150.5        |
| 1100     | 0.972                 | 171.4         | 0.335                 | 146.4         | 0.005                 | 89.90         | 0.966                 | -152.2        |
| 1150     | 0.963                 | 170.8         | 0.396                 | 148.5         | 0.005                 | 87.51         | 0.977                 | -153.7        |
| 1200     | 0.964                 | 169.9         | 0.461                 | 148.8         | 0.006                 | 89.25         | 0.971                 | -155.2        |
| 1250     | 0.956                 | 169.0         | 0.531                 | 148.2         | 0.007                 | 86.98         | 0.977                 | -156.8        |
| 1300     | 0.948                 | 167.8         | 0.604                 | 146.9         | 0.007                 | 85.08         | 0.982                 | -157.9        |
| 1350     | 0.939                 | 167.0         | 0.685                 | 144.8         | 0.008                 | 82.40         | 0.986                 | -159.5        |
| 1400     | 0.927                 | 165.7         | 0.772                 | 142.2         | 0.008                 | 79.69         | 0.988                 | -160.7        |
| 1450     | 0.910                 | 164.5         | 0.869                 | 138.7         | 0.009                 | 77.79         | 0.994                 | -162.1        |
| 1500     | 0.889                 | 163.2         | 0.975                 | 134.7         | 0.010                 | 75.79         | 0.991                 | -163.4        |
| 1550     | 0.861                 | 161.9         | 1.093                 | 129.7         | 0.010                 | 72.86         | 0.993                 | -164.7        |
| 1600     | 0.821                 | 160.9         | 1.221                 | 123.8         | 0.011                 | 69.89         | 0.996                 | -166.0        |
| 1650     | 0.780                 | 160.1         | 1.356                 | 116.7         | 0.012                 | 63.71         | 0.984                 | -167.4        |
| 1700     | 0.722                 | 160.6         | 1.491                 | 108.3         | 0.013                 | 57.70         | 0.985                 | -168.5        |
| 1750     | 0.666                 | 162.5         | 1.606                 | 98.77         | 0.014                 | 49.85         | 0.977                 | -169.6        |
| 1800     | 0.618                 | 167.0         | 1.687                 | 88.09         | 0.014                 | 41.19         | 0.970                 | -170.8        |
| 1850     | 0.603                 | 173.3         | 1.706                 | 76.98         | 0.013                 | 32.65         | 0.958                 | -171.3        |
| 1900     | 0.614                 | 179.7         | 1.673                 | 66.08         | 0.012                 | 25.40         | 0.954                 | -171.9        |
| 1950     | 0.654                 | -175.6        | 1.591                 | 55.96         | 0.011                 | 20.73         | 0.945                 | -172.3        |
| 2000     | 0.701                 | -173.5        | 1.484                 | 47.04         | 0.010                 | 15.11         | 0.947                 | -172.6        |
| 2050     | 0.747                 | -172.7        | 1.364                 | 39.29         | 0.008                 | 10.13         | 0.947                 | -173.0        |
| 2100     | 0.783                 | -172.6        | 1.242                 | 32.87         | 0.006                 | 6.333         | 0.945                 | -173.6        |
| 2150     | 0.816                 | -172.9        | 1.136                 | 27.69         | 0.004                 | 15.63         | 0.944                 | -173.9        |
| 2200     | 0.842                 | -173.6        | 1.042                 | 23.26         | 0.004                 | 42.20         | 0.944                 | -174.2        |
| 2250     | 0.864                 | -174.2        | 0.961                 | 19.26         | 0.005                 | 57.76         | 0.948                 | -174.6        |
| 2300     | 0.882                 | -175.0        | 0.888                 | 15.75         | 0.006                 | 62.56         | 0.948                 | -175.2        |
| 2350     | 0.894                 | -175.7        | 0.822                 | 12.69         | 0.008                 | 59.72         | 0.949                 | -175.7        |
| 2400     | 0.906                 | -176.4        | 0.764                 | 9.857         | 0.009                 | 49.09         | 0.951                 | -176.1        |
| 2450     | 0.910                 | -176.9        | 0.712                 | 7.587         | 0.008                 | 39.24         | 0.955                 | -176.5        |

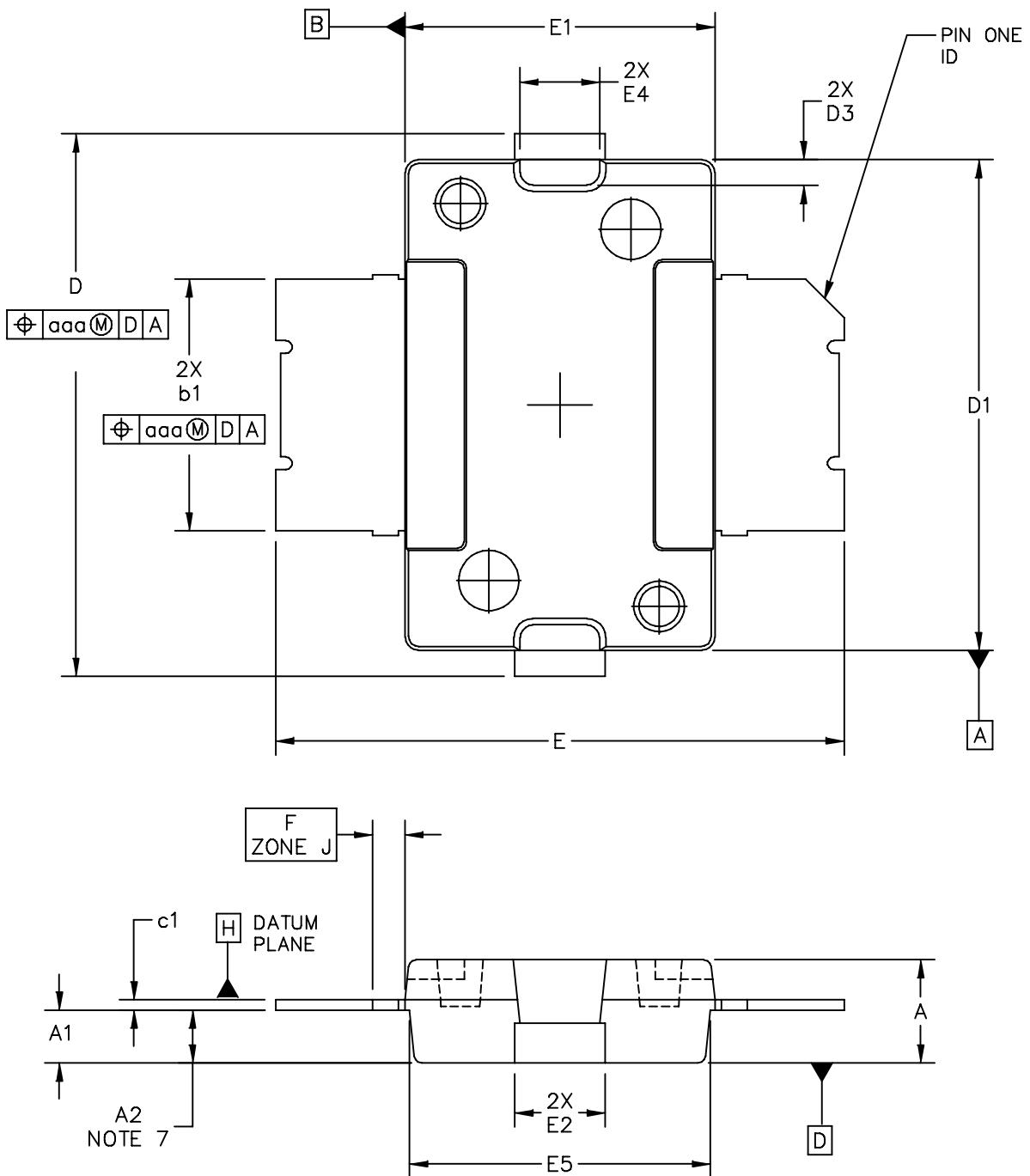
(continued)

**Table 9. Common Source Scattering Parameters ( $V_{DD} = 28$  V,  $I_{DQ} = 126$  mA,  $T_A = 25^\circ\text{C}$ , 50 ohm system) (continued)**

| f<br>MHz | $S_{11}$   |               | $S_{21}$   |               | $S_{12}$   |               | $S_{22}$   |               |
|----------|------------|---------------|------------|---------------|------------|---------------|------------|---------------|
|          | $ S_{11} $ | $\angle \phi$ | $ S_{21} $ | $\angle \phi$ | $ S_{12} $ | $\angle \phi$ | $ S_{22} $ | $\angle \phi$ |
| 2500     | 0.923      | -177.5        | 0.666      | 5.462         | 0.006      | 42.56         | 0.957      | -177.2        |
| 2550     | 0.927      | -178.0        | 0.625      | 3.680         | 0.006      | 52.25         | 0.962      | -177.8        |
| 2600     | 0.937      | -178.8        | 0.591      | 1.864         | 0.006      | 60.26         | 0.961      | -178.4        |
| 2650     | 0.937      | -179.0        | 0.559      | 0.237         | 0.007      | 64.14         | 0.964      | -179.1        |
| 2700     | 0.942      | -179.8        | 0.529      | -1.378        | 0.007      | 65.62         | 0.964      | -179.6        |
| 2750     | 0.945      | -179.9        | 0.504      | -2.768        | 0.007      | 64.71         | 0.964      | 179.7         |
| 2800     | 0.946      | 179.5         | 0.479      | -4.088        | 0.007      | 67.58         | 0.966      | 179.4         |
| 2850     | 0.950      | 179.3         | 0.456      | -5.412        | 0.007      | 75.44         | 0.966      | 178.8         |
| 2900     | 0.949      | 178.8         | 0.436      | -6.305        | 0.008      | 82.04         | 0.964      | 178.3         |
| 2950     | 0.952      | 178.5         | 0.419      | -7.279        | 0.009      | 83.60         | 0.967      | 177.9         |
| 3000     | 0.950      | 178.4         | 0.402      | -8.087        | 0.011      | 83.41         | 0.968      | 177.4         |
| 3050     | 0.958      | 177.9         | 0.387      | -9.138        | 0.012      | 81.35         | 0.964      | 176.8         |
| 3100     | 0.953      | 177.7         | 0.373      | -9.904        | 0.013      | 77.45         | 0.969      | 176.4         |
| 3150     | 0.957      | 177.2         | 0.362      | -10.86        | 0.014      | 70.98         | 0.970      | 176.2         |
| 3200     | 0.960      | 177.4         | 0.350      | -11.79        | 0.013      | 67.00         | 0.970      | 175.5         |

**MRF6S20010NR1 MRF6S20010GNR1**

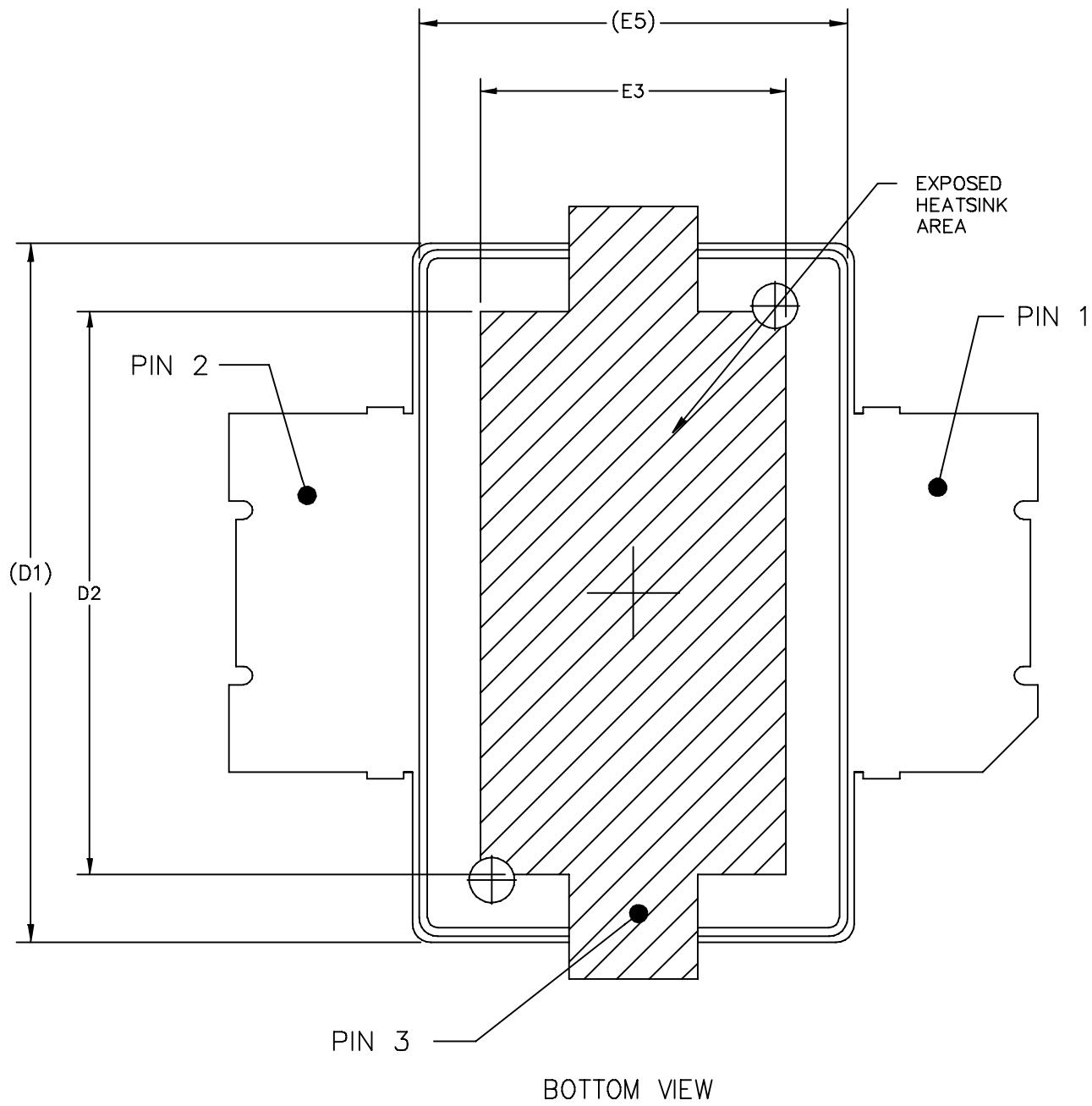
## PACKAGE DIMENSIONS



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| TITLE:<br><br>TO-270<br>SURFACE MOUNT                   |  | DOCUMENT NO: 98ASH98117A<br><br>CASE NUMBER: 1265-09<br><br>STANDARD: JEDEC TO-270 AA | REV: K<br><br>29 JUN 2007  |

**MRF6S20010NR1 MRF6S20010GNR1**

RF Device Data  
Freescale Semiconductor



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| TITLE:<br>TO-270<br>SURFACE MOUNT                       | DOCUMENT NO: 98ASH98117A  | REV: K                     |
|   | CASE NUMBER: 1265-09      | 29 JUN 2007                |
|   | STANDARD: JEDEC TO-270 AA |                            |

MRF6S20010NR1 MRF6S20010GNR1

NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE -H- IS LOCATED AT TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS "D1" AND "E1" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 PER SIDE. DIMENSIONS "D1 AND "E1" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSION "b1" DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 TOTAL IN EXCESS OF THE "b1" DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-.
7. DIMENSION "A2" APPLIES WITHIN ZONE "J" ONLY.
8. DIMENSIONS "D" AND "E2" DO NOT INCLUDE MOLD PROTRUSION. OVERALL LENGTH INCLUDING MOLD PROTRUSION SHOULD NOT EXCEED 0.430 INCH FOR DIMENSION "D" AND 0.080 INCH FOR DIMENSION "E2". DIMENSIONS "D" AND "E2" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -D-.

STYLE 1:

PIN 1 - DRAIN  
 PIN 2 - GATE  
 PIN 3 - SOURCE

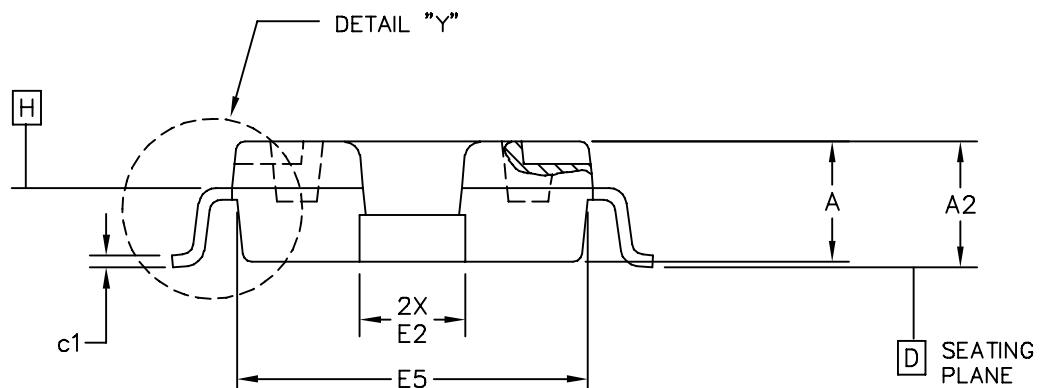
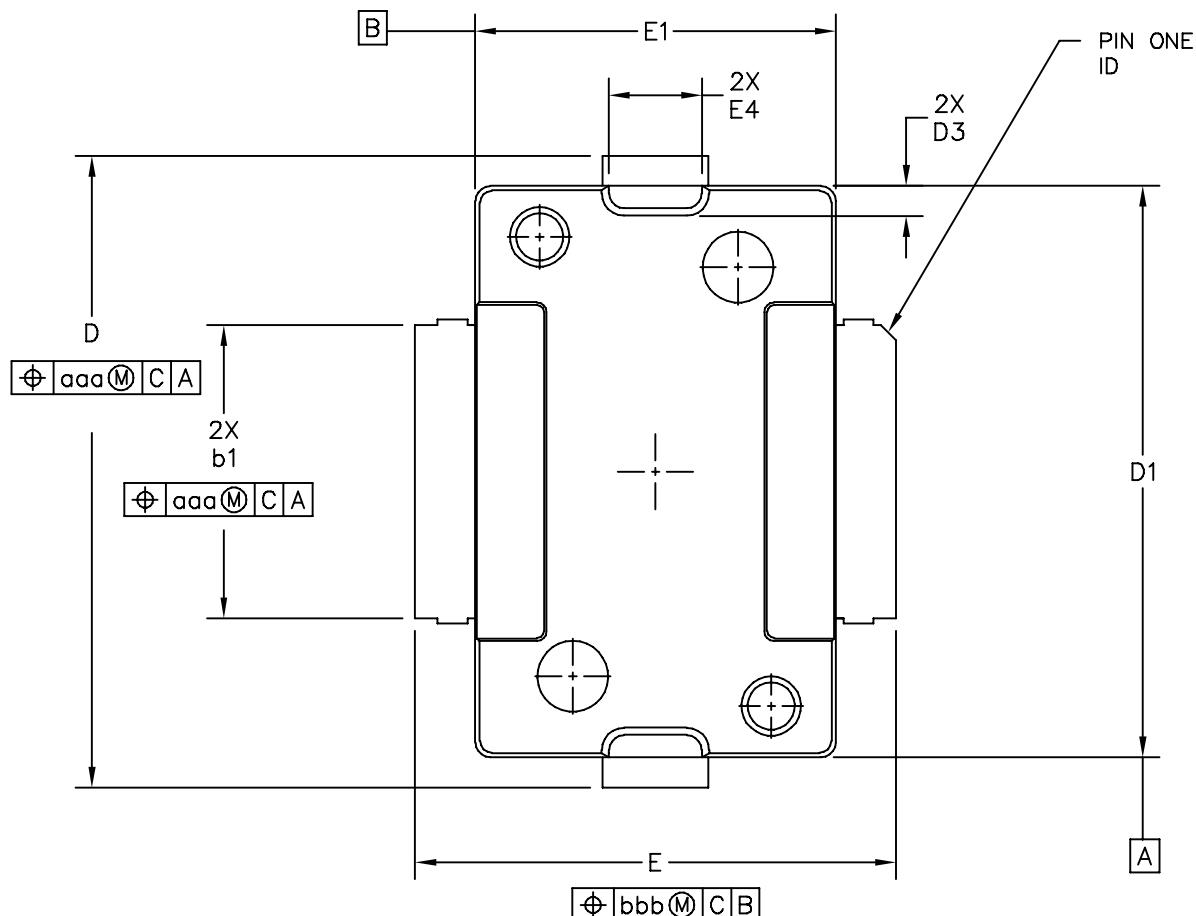
| DIM | INCH |      | MILLIMETER |       | DIM | INCH |      | MILLIMETER |      |
|-----|------|------|------------|-------|-----|------|------|------------|------|
|     | MIN  | MAX  | MIN        | MAX   |     | MIN  | MAX  | MIN        | MAX  |
| A   | .078 | .082 | 1.98       | 2.08  | F   | .025 | BSC  | 0.64       | BSC  |
| A1  | .039 | .043 | 0.99       | 1.09  | b1  | .193 | .199 | 4.90       | 5.06 |
| A2  | .040 | .042 | 1.02       | 1.07  | c1  | .007 | .011 | 0.18       | 0.28 |
| D   | .416 | .424 | 10.57      | 10.77 | aaa |      | .004 |            | 0.10 |
| D1  | .378 | .382 | 9.60       | 9.70  |     |      |      |            |      |
| D2  | .290 | ---- | 7.37       | ----  |     |      |      |            |      |
| D3  | .016 | .024 | 0.41       | 0.61  |     |      |      |            |      |
| E   | .436 | .444 | 11.07      | 11.28 |     |      |      |            |      |
| E1  | .238 | .242 | 6.04       | 6.15  |     |      |      |            |      |
| E2  | .066 | .074 | 1.68       | 1.88  |     |      |      |            |      |
| E3  | .150 | ---- | 3.81       | ----  |     |      |      |            |      |
| E4  | .058 | .066 | 1.47       | 1.68  |     |      |      |            |      |
| E5  | .231 | .235 | 5.87       | 5.97  |     |      |      |            |      |

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MECHANICAL OUTLINE

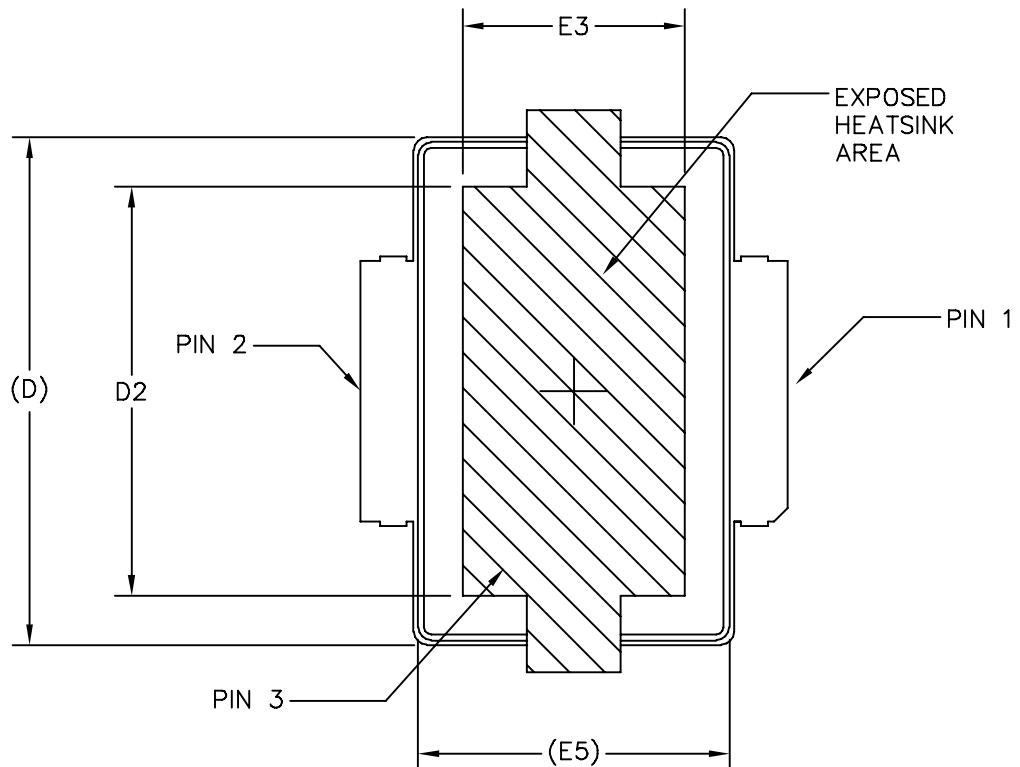
PRINT VERSION NOT TO SCALE

|                                       |                           |             |
|---------------------------------------|---------------------------|-------------|
| TITLE:<br><br>TO-270<br>SURFACE MOUNT | DOCUMENT NO: 98ASH98117A  | REV: K      |
|                                       | CASE NUMBER: 1265-09      | 29 JUN 2007 |
|                                       | STANDARD: JEDEC TO-270 AA |             |

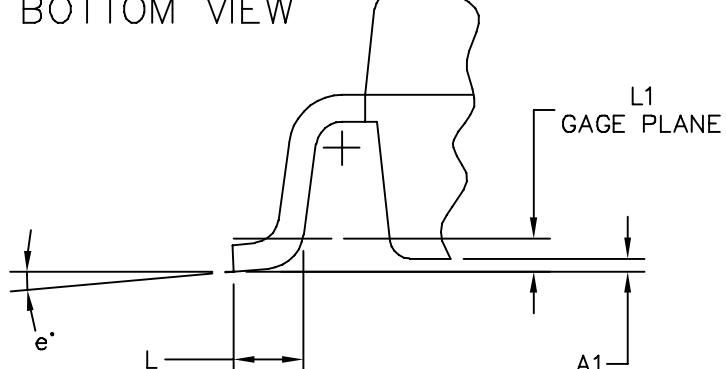


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| TITLE:<br><br>TO-270<br>GULL WING                       | DOCUMENT NO: 98ASA99301D  | REV: C                     |
|   | CASE NUMBER: 1265A-03     | 02 JUL 2007                |
|   | STANDARD: JEDEC TO-270 BA |                            |

MRF6S20010NR1 MRF6S20010GNR1



BOTTOM VIEW



DETAIL "Y"

|   |  |                            |
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| TITLE:<br><br>TO-270<br>GULL WING                       | DOCUMENT NO: 98ASA99301D<br><br>CASE NUMBER: 1265A-03<br><br>STANDARD: JEDEC TO-270 BA | REV: C<br><br>02 JUL 2007  |

NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE -H- IS LOCATED AT TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS "D1" AND "E1" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 PER SIDE. DIMENSIONS "D1" AND "E1" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSION b1 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 TOTAL IN EXCESS OF THE b1 DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-.
7. DIMENSIONS "D" AND "E2" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .003 PER SIDE. DIMENSIONS "D" AND "E2" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -D-.

STYLE 1:

PIN 1 – DRAIN  
 PIN 2 – GATE  
 PIN 3 – SOURCE

| DIM | INCH |      | MILLIMETER |       | DIM | INCH |      | MILLIMETER |      |  |
|-----|------|------|------------|-------|-----|------|------|------------|------|--|
|     | MIN  | MAX  | MIN        | MAX   |     | MIN  | MAX  | MIN        | MAX  |  |
| A   | .078 | .082 | 1.98       | 2.08  | L   | .018 | .024 | 0.46       | 0.61 |  |
| A1  | .001 | .004 | 0.02       | 0.10  | L1  | .01  | BSC  | 0.25       | BSC  |  |
| A2  | .077 | .088 | 1.96       | 2.24  | b1  | .193 | .199 | 4.90       | 5.06 |  |
| D   | .416 | .424 | 10.57      | 10.77 | c1  | .007 | .011 | 0.18       | 0.28 |  |
| D1  | .378 | .382 | 9.60       | 9.70  | e   | 2°   | 8°   | 2°         | 8°   |  |
| D2  | .290 | –    | 7.37       | –     | aaa | .004 |      | 0.10       |      |  |
| D3  | .016 | .024 | 0.41       | 0.61  |     |      |      |            |      |  |
| E   | .316 | .324 | 8.03       | 8.23  |     |      |      |            |      |  |
| E1  | .238 | .242 | 6.04       | 6.15  |     |      |      |            |      |  |
| E2  | .066 | .074 | 1.68       | 1.88  |     |      |      |            |      |  |
| E3  | .150 | –    | 3.81       | –     |     |      |      |            |      |  |
| E4  | .058 | .066 | 1.47       | 1.68  |     |      |      |            |      |  |
| E5  | .231 | .235 | 5.87       | 5.97  |     |      |      |            |      |  |

|   |                           |                            |
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| TITLE:<br><br>TO-270<br>GULL WING                       | DOCUMENT NO: 98ASA99301D  | REV: C                     |
|   | CASE NUMBER: 1265A-03     | 02 JUL 2007                |
|   | STANDARD: JEDEC TO-270 BA |                            |

MRF6S20010NR1 MRF6S20010GNR1

## PRODUCT DOCUMENTATION, TOOLS AND SOFTWARE

Refer to the following documents to aid your design process.

### Application Notes

- AN1907: Solder Reflow Attach Method for High Power RF Devices in Plastic Packages
- AN1955: Thermal Measurement Methodology of RF Power Amplifiers
- AN3789: Clamping of High Power RF Transistors and RFICs in Over-Molded Plastic Packages

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

### Software

- Electromigration MTTF Calculator
- RF High Power Model

For Software and Tools, do a Part Number search at <http://www.freescale.com>, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description  |
|----------|-----------|--|
| 2        | Dec. 2008 | <ul style="list-style-type: none"><li>• Changed Storage Temperature Range in Max Ratings table from -65 to +175 to -65 to +150 for standardization across products, p. 1</li><li>• Added Case Operating Temperature limit to the Maximum Ratings table and set limit to 150°C, p. 1</li><li>• Operating Junction Temperature increased from 200°C to 225°C in Maximum Ratings table, related “Continuous use at maximum temperature will affect MTTF” footnote added and changed 200°C to 225°C in Capable Plastic Package bullet, p. 1</li><li>• Corrected V<sub>DS</sub> to V<sub>DD</sub> in the RF test condition voltage callout for V<sub>GS(Q)</sub>, On Characteristics table, p. 2</li><li>• Corrected C<sub>iss</sub> test condition to indicate AC stimulus on the V<sub>GS</sub> connection versus the V<sub>DS</sub> connection, Dynamic Characteristics table, p. 2</li><li>• Updated Part Numbers in Tables 6, 7, 8, Component Designations and Values, to RoHS compliant part numbers, p. 4, 10, 14</li><li>• Adjusted scale for Fig. 7, Intermodulation Distortion Products versus Tone Spacing, to better match the device’s capabilities, p. 6</li><li>• Removed lower voltage tests from Fig. 10, Power Gain versus Output Power, due to fixed tuned fixture limitations, p. 7</li><li>• Replaced Fig. 12, MTTF versus Junction Temperature with updated graph. Removed Amps<sup>2</sup> and listed operating characteristics and location of MTTF calculator for device, p. 7</li><li>• Removed ALT1 definition from Fig. 21, Single-Carrier CCDF N-CDMA, given no supporting performance information provided, p. 13</li><li>• Replaced Case Outline 1265-08 with 1265-09, Issue K, p. 1, 20-22. Corrected cross hatch pattern in bottom view and changed its dimensions (D2 and E3) to minimum value on source contact (D2 changed from Min-Max .290-.320 to .290 Min; E3 changed from Min-Max .150-.180 to .150 Min). Added JEDEC Standard Package Number.</li><li>• Replaced Case Outline 1265A-02 with 1265A-03, Issue C, p. 1, 23-25. Corrected cross hatch pattern and its dimensions (D2 and E2) on source contact (D2 changed from Min-Max .290-.320 to .290 Min; E3 changed from Min-Max .150-.180 to .150 Min). Added pin numbers. Corrected mm dimension L for gull-wing foot from 4.90-.506 Min-Max to 0.46-0.61 Min-Max. Added JEDEC Standard Package Number.</li><li>• Added Product Documentation and Revision History, p. 26</li></ul> |
| 3        | June 2009 | <ul style="list-style-type: none"><li>• Corrected decimal placement for C<sub>iss</sub> (changed 0.12 pF to 120 pF) and C<sub>oss</sub> (changed 0.02 pF to 20 pF), Dynamic Characteristics table, p. 2</li><li>• Added footnote, Measurement made with device in straight lead configuration before any lead forming operation is applied, to Functional Tests table, p. 2.</li><li>• Added AN3789, Clamping of High Power RF Transistors and RFICs in Over-Molded Plastic Packages to Product Documentation, Application Notes, p. 26</li><li>• Added Electromigration MTTF Calculator and RF High Power Model availability to Product Software, p. 26</li></ul>   |

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